## Transient phenomena in scintillation materials



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## Outline

- Motivation
- **D** Experimental technique
- Results on GAGG:Ce
  - Experimental results on differential optical absorption in GAGG:Ce with and without Mg codoping
  - Modeling of carrier population kinetics
- Results on LSO:Ce and LYSO:Ce
- Conclusions

This research was focused on



## fast scintillators



### Let it be 10 ps

for high-energy physics and medical imaging









## **EXPERIMENTAL TECHNIQUE**





## subpicosecond time resolution



### selective excitation



Absoption spectra of GAGG without intentional doping (courtesy of Dr. O.Sidletski), doped with Ce and codoped with Ce, Mg



Energy levels of Ce<sup>3+</sup> in respect of valence (VB) and conduction (CB) bands of GAGG



## revealing spectral and time features





## revealing spectral and time features



# MATERIALS

MULTICOMPONENT

# STUDIED

#### **Multicomponent garnet-type scintillator**

GAGG:Ce

## gadolinium aluminum gallium garnet

Gd<sub>3</sub>Al<sub>2</sub>Ga<sub>3</sub>O<sub>12</sub>

## fast but might be faster





**Ceres**, a goddess of agriculture, grain crops, fertility and motherly relationships

garnet



Lutetium-yttrium oxyorthosilicate LYSO:Ce Lu<sub>2(1-x)</sub>Y<sub>2x</sub>SiO<sub>5</sub>:Ce and probably fast enough **Results** 

# GAGG:Ce without and with codoping

Differential absorption of GAGG:Ce as a function of probe photon energy and delay between pump and probe pulses at pump photon energy of 2.8 eV







No DA in GAGG without intentional Ce doping Differential absorption of GAGG:Ce as a function of probe photon energy and delay between pump and probe pulses at pump photon energy of 2.8 eV



with Mg-codoping 10000 11.382 10.586 1000 Probe delay time (ps) 9.71 8,993 8.197 7.401 100 6.605 5.801 5.012 10 4.214 3.42 2.624 1.828 1.031 0.235 0.5 0 -0.5 -1 1.6 1.8 2 2.2 2.4 1.4 Probe photon energy (eV)



The differential absorption in the vicinity of 1.4 eV reflects the population of the lowest excited Ce<sup>3+</sup> level

#### No DA in GAGG without intentional Ce doping

Differential absorption of GAGG:Ce as a function of probe photon energy and delay between pump and probe pulses at pump photon energy of 3.63 eV



#### with Mg-codoping





Kinetics of differential absorption at 1.4 eV in GAGG samples with different doping

#### Differential absorption kinetics in GAGG:Ce and GAGG:Ce,Mg at different temperatures



Pump 2.8 eV (to  $Ce^{3+} 5d_1$  state) Pump 3.6 eV (to  $Ce^{3+} 5d_2$  state)

## Simulation of population kinetics



## Simulation of population kinetics



4f

Introduction of Mg decreases the influence of traps

## Simulation of population kinetics



4f

The time of intracenter  $5d_2 - 5d_1$  relaxation at Ce<sup>3+</sup> in GAGG:Ce equals 500 fs **Results** 

## LSO:Ce

## **Differential absorption in LSO**



Conduction band



The fast component in the decay of differential absorption is caused by free electron absorption

## **Differential absorption of three LSO ingots**



Are we able to identify a clear and reliably measurable figure of merit for fast response?

Please attend the presentation of Dr. Saulius Nargelas October 10, 10 PM Results

## Nonequilibrium carrier dynamics LYSO:Ce versus LSO:Ce



LYSO

LSO

pump@5.91eV (210nm)

#### **Comparison of DA spectra & kinetics**

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#### **Comparison of DA spectra & kinetics**



#### **Comparison of DA spectra & kinetics**

#### Absorption decay after 5.91 eV pump



### **Conclusions on GAGG:Ce**

- □ The rise of the differential absorption at resonant intracenter excitation of Ce<sup>3+</sup> ions from the ground state into the first excited level 5d<sup>1</sup> is instantaneous within the time resolution of 300 fs.
- □ The slow rise time component of differential absorption, observed when Ce<sup>3+</sup> ions were excited into the second excited level 5d<sub>2</sub>, is due to <u>trapping</u> of the nonequilibrium electrons moving through the crystal matrix.

#### $\Box \quad Intracenter 5d_2 - 5d_1 relaxation time in Ce^{3+} equals 500 fs$

Suppression of the slow component in the front of the differential absorption response is achieved by <u>codoping with Mg even at the codoping levels as small</u> <u>as 10 ppm</u>, which are insufficient to significantly change the valence state of cerium ions from Ce<sup>3+</sup> to Ce<sup>4+</sup>.

### **Conclusions on LSO:Ce and LYSO:Ce**

- The initial rise time of differential absorption due to free electrons is in subpicosecond domain for both LSO:Ce and LYSO:Ce.
- Population of the emitting level of Ce<sup>3+</sup> in LYSO:Ce is delayed by several picoseconds due to migration of nonequilibrium electrons through the matrix.
- □ The decay in population of the lowest excited Ce level proceeds at the same rate both in LYSO:Ce and LSO:Ce.

## Thank you for your attention

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